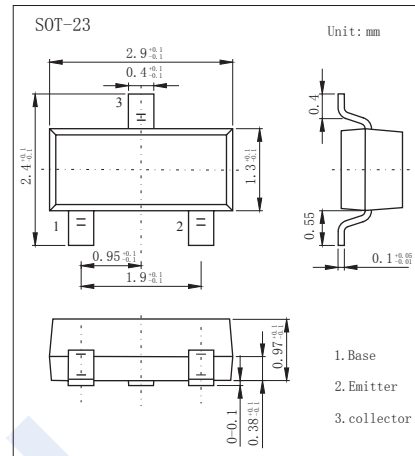


NPN Transistors

2SC3265-HF

■ Features

- High DC current gain
- Low saturation voltage
- Complementary to 2SA1298-HF
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V _{CB0}	30	V
Collector - Emitter Voltage	V _{CE0}	25	
Emitter - Base Voltage	V _{EB0}	5	
Collector Current - Continuous	I _C	800	mA
Base Current	I _B	160	
Collector Power Dissipation	P _C	200	mW
Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{stg}	-55 to 150	

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{CB0}	I _C = 100 μA, I _E = 0	30			V
Collector- emitter breakdown voltage	V _{CE0}	I _C = 10 mA, I _B = 0	25			
Emitter - base breakdown voltage	V _{EB0}	I _E = 100 μA, I _C = 0	5			
Collector-base cut-off current	I _{CB0}	V _{CB} = 30 V, I _E = 0			0.1	μA
Emitter cut-off current	I _{EB0}	V _{EB} = 5V, I _C = 0			0.1	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 500 mA, I _B = 20 mA			0.4	V
Base - emitter saturation voltage	V _{BE(sat)}	I _C = 500 mA, I _B = 20 mA		0.72	1	
Base - emitter voltage	V _{BE}	V _{CE} = 1V, I _C = 10mA	0.5		0.8	
DC current gain	h _{FE}	V _{CE} = 1V, I _C = 100mA	100		320	
		V _{CE} = 1V, I _C = 800mA	40			
Collector output capacitance	C _{ob}	V _{CB} = 10V, I _E = 0, f=1MHz		13		pF
Transition frequency	f _T	V _{CE} = 5V, I _C = 10mA		120		MHz

■ Classification of h_{FE}(1)

Type	2SC3265-O-HF	2SC3265-Y-HF
Range	100-200	160-320
Marking	EO _F	EY _F

NPN Transistors

2SC3265-HF

■ Typical Characteristics

